

Sensitive Gate Sillicon Controlled Rectifiers Reverse Blocking Thyristors

SCRs 8 AMPERES RMS 600 VOLTS

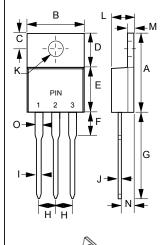
TO-220AB

FEATURES

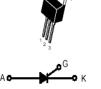
- Blocking Voltage of 600 Volts
- On-State Current Rating of 8 Amperes RMS at 80℃
- High Surge Current Capability 80 Amperes
- Rugged, Economical TO220AB Package
- Glass Passivated Junctions for Reliability and Uniformity
- Minimum and Maximum Values of IGT, VGT an IH Specified for Ease of Design
- Pb-Free Package

MECHANICAL DATA

- Case: Molded plastic
- Weight: 0.07 ounces, 2.0 grams



TO-220AB DIM. MIN. MAX. 14.22 15.88 В 9.65 10.67 С 2.54 3.43 D 5.84 6.86 Ε 8.26 9.28 6.35 G 12.70 14.73 2.79 2.29 0.51 1.14 0.67 0.40 K 4.09 Ø 3.53 Ø 3.56 4.83 Μ 1.40 1.14 Ν 2.03 2.92 0 1.37 1.17 All Dimensions in millimeter



| | PIN ASSIGNMENT |
|---|----------------|
| 1 | Cathode |
| 2 | Anode |
| 3 | Gate |
| 4 | Anode |

MAXIMUM RATINGS (Tj= 25℃ unless otherwise noticed)

| Rating | Symbol | Value | Unit |
|---|---------------|------------------|------------------|
| Peak Repetitive Off– State Voltage (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz; Gate Open) | VDRM, VRRM | 600 | Volts |
| On-State RMS Current (180° Conduction Angles, Tc = 80°C) | IT(RMS) | 8 | Amp |
| Peak Non-Repetitive Surge Current (1/2 Cycle, Slne Wave 60 Hz, Tj = 25℃) | Ітѕм | 80 | Amp |
| Circuit Fusing Consideration (t = 8.3 ms) | l t | 26.5 | A ² s |
| Forward Peak Gate Power (Pulse Width ≦ 1.0 us, Tc = 80°C) | Рдм | 5.0 | Watt |
| Forward Average Gate Power (t= 8.3 ms, Tc = 80℃) | PG(AV) | 0.5 | Watt |
| Forward Peak Gate Current (Pulse Width ≦ 1.0 us, Tc = 80°C) | lgм | 2.0 | Amp |
| Operating Junction Temperature Range | TJ | -40 to +125 | °C |
| Storage Temperature Range | Tstg | -40 to +150 | °C |
| Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for | RE | V.8, Dec-2010, K | TXC11 |

Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded



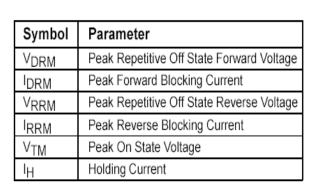
| THED | МΛΙ | CHADA | CTERIS1 | 30T |
|------|-------|-------|---------|-----|
| IDEN | VIAL. | CHARA | CIENIO | 100 |

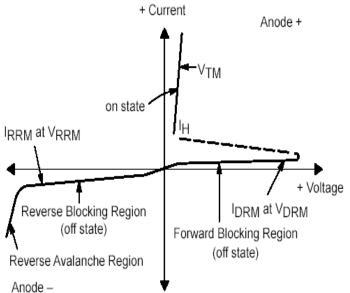
| Characteristic | Symbol | Value | Unit |
|--|----------------|-------------|------------------------|
| Thermal Resistance - Junction to Case - Junction to Ambient | RthJC RthJA | 2.2 62.5 | °C/W |
| Maximum Lead Temperature for Soldering Purposes 1/8 from Case for 10 Seconds | TL | 260 | $^{\circ}\!\mathbb{C}$ |

| Characteristics | Symbol | Min | Тур | Max | Unit |
|---|--------------|-----|------|-----------|----------|
| OFF CHARACTERISTICS | | | | | |
| Peak Reptitive Forward or Reverse Blocking Current TJ=25°C (VD=Rated VDRM and VRRM; Gate Open) TJ=125°C | IDRM IRRM | | | 10 2.0 | uA mA |
| ON CHARACTERISTICS | | | | | |
| Peak Forward On-State Voltage (ITM= 16A Peak @Tp \leq 2.0 ms, Duty Cycle \leq 2%) | VTM | | | 1.8 | Volts |
| Gate Trigger Current (VD = 12 V; RL = 100 Ohms) | lgт | 2.0 | 7.0 | 15 | mA |
| Holding Current (VD = 12 V, Gate Open, Initiating Current = 200 mA) | lΗ | 4.0 | 17 | 30 | mA |
| Latch Current (VD = 12 V, IG = 15 mA) | lL | 6.0 | 20 | 40 | mA |
| Gate Trigger Voltage (VD = 12 V; RL =100 Ohms) | VgT | 0.5 | 0.65 | 1.0 | Volts |
| Gate Non - Trigger Voltage (VD = 12V, RL =100 Ohms) TJ=125℃ | VGD | 0.2 | | | Volts |
| DYNAMIC CHARACTERISTICS | | | | | |
| Critical Rate of Rise of Off-State Voltage (VD=Rated VDRM,Exponential Waveform, Gate Open,TJ=125℃) | dv/dt | 100 | 250 | | V/us |
| Repetitive Critical Rate of Rise of On-State Current IPK=50A,Pw=40 usec,diG/dt=1A/usec,lgt=50mA | di/dt | | | 50 | A/us |

^{*}Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.







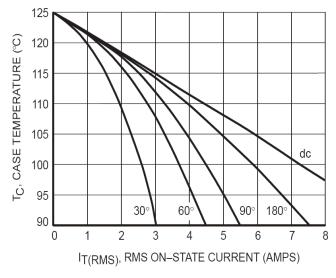


Figure 1. Typical RMS Current Derating

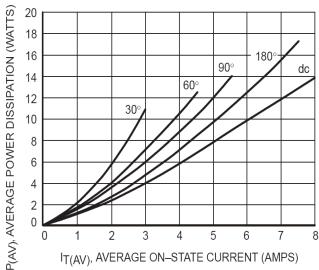
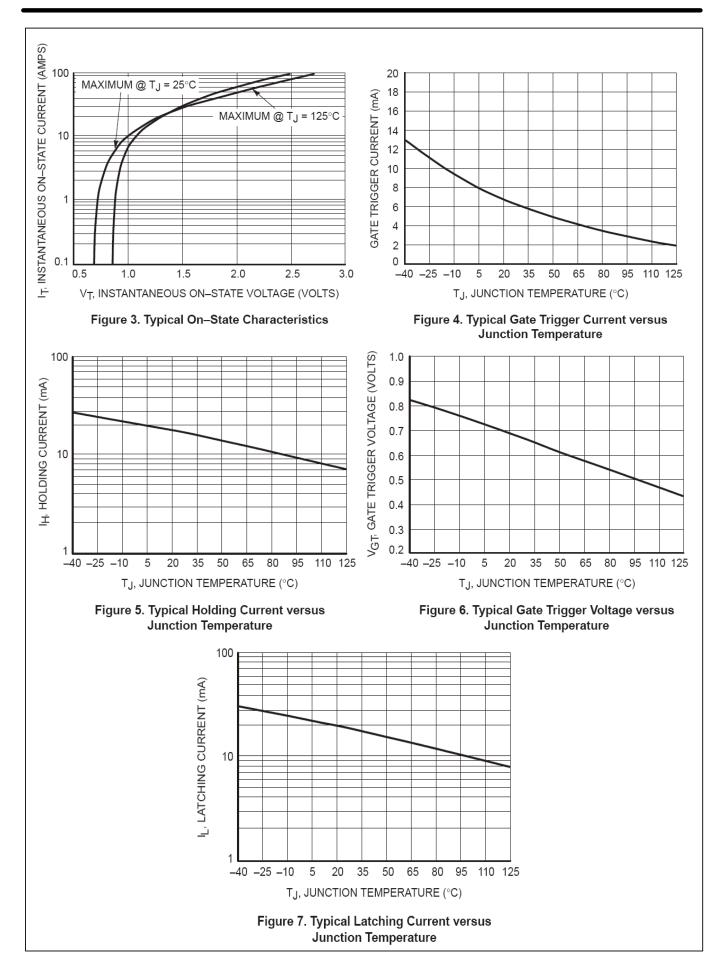


Figure 2. On-State Power Dissipation







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